NSN 5962-01-339-4899

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View Online at https://aerobasegroup.com/nsn/5962-01-339-4899

Overall Length:

Between 0.554 inches and 0.572 inches

Overall Height:

Between 0.055 inches and 0.125 inches

Overall Width:

Between 0.554 inches and 0.572 inches

Body Length:

Between 0.554 inches and 0.572 inches

Body Width:

Between 0.554 inches and 0.572 inches

Body Height:

Between 0.055 inches and 0.125 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and static operation and positive outputs and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

44 input

Current Rating Per Characteristic:

185.00 milliamperes supply

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

120.00 nanoseconds access

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

48 leadless

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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